

DAC088S085 8-Bit Micro Power OCTAL Digital-to-Analog Converter with Rail-to-Rail Outputs

Check for Samples: DAC088S085

FEATURES

- · Guaranteed Monotonicity
- Low Power Operation
- Rail-to-Rail Voltage Output
- Daisy Chain Capability
- Power-on Reset to 0V
- Simultaneous Output Updating
- Individual Channel Power Down Capability
- Wide power supply range (+2.7V to +5.5V)
- Dual Reference Voltages with range of 0.5V to V_{A}
- Operating Temperature Range of −40°C to

+125°C

Industry's Smallest Package

APPLICATIONS

- Battery-Powered Instruments
- Digital Gain and Offset Adjustment
- Programmable Voltage & Current Sources
- Programmable Attenuators
- Voltage Reference for ADCs
- Sensor Supply Voltage
- Range Detectors

DESCRIPTION

The DAC088S085 is a full-featured, general purpose OCTAL 8-bit voltage-output digital-to-analog converter (DAC) that can operate from a single +2.7V to +5.5V supply and consumes 1.95 mW at 3V and 4.85 mW at 5V. The DAC088S085 is packaged in a 16-lead LLP package and a 16-lead TSSOP package. The LLP package makes the DAC088S085 the smallest OCTAL DAC in its class. The on-chip output amplifiers allow rail-to-rail output swing and the three wire serial interface operates at clock rates up to 40 MHz over the entire supply voltage range. Competitive devices are limited to 25 MHz clock rates at supply voltages in the 2.7V to 3.6V range. The serial interface is compatible with standard SPI™, QSPI, MICROWIRE and DSP interfaces. The DAC088S085 also offers daisy chain operation where an unlimited number of DAC088S085s can be updated simultaneously using a single serial interface.

There are two references for the DAC088S085. One reference input serves channels A through D while the other reference serves channels E through H. Each reference can be set independently between 0.5V and V_A , providing the widest possible output dynamic range. The DAC088S085 has a 16-bit input shift register that controls the mode of operation, the power-down condition, and the DAC channels' register/output value. All eight DAC outputs can be updated simultaneously or individually.

A power-on reset circuit ensures that the DAC outputs power up to zero volts and remain there until there is a valid write to the device. The power-down feature of the DAC088S085 allows each DAC to be independently powered with three different termination options. With all the DAC channels powered down, power consumption reduces to less than 0.3 μ W at 3V and less than 1 μ W at 5V. The low power consumption and small packages of the DAC088S085 make it an excellent choice for use in battery operated equipment.

The DAC088S085 is one of a family of pin compatible DACs, including the 10-bit DAC108S085 and the 12-bit DAC128S085. All three parts are offered with the same pinout, allowing system designers to select a resolution appropriate for their application without redesigning their printed circuit board. The DAC088S085 operates over the extended industrial temperature range of -40°C to +125°C.

Table 1. Key Specifications

	VALUE	UNIT
Resolution	8	bits
INL	±0.5	LSB (max)

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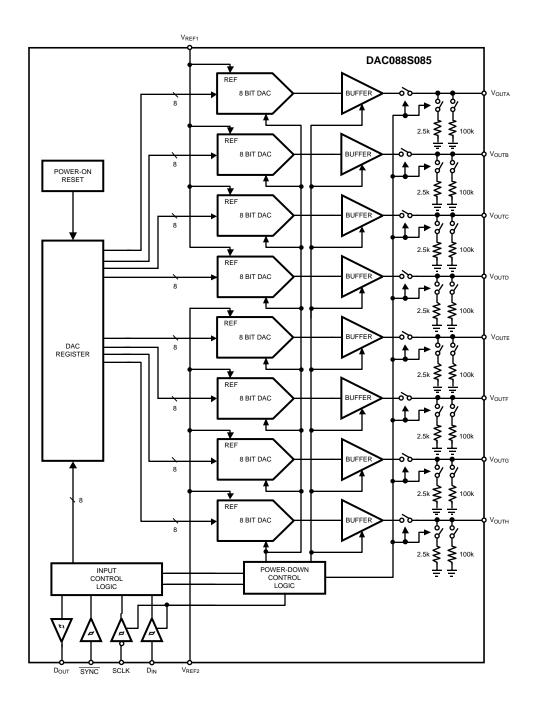


Table 1. Key Specifications (continued)

		VALUE	UNIT
DNL		+0.15 / -0.1	LSB (max)
Settling Time		4.5 µs (max)	
Zero Code Error		+15 mV (max)	
Full-Scale Error		-0.75 %FSR (max)	
Supply Power	Normal	1.95 mW (3V) / 4.85 mW (5V) typ	
	Power Down	0.3 μW (3V) / 1 μW (5V) typ	

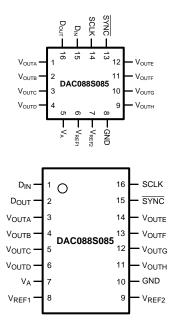


Block Diagram





Pin Configuration



Pin Functions

Pin Descriptions

LLP Pin No.	TSSOP Pin No.	Symbol	Туре	Description
1	3	V _{OUTA}	Analog Output	Channel A Analog Output Voltage.
2	4	V _{OUTB}	Analog Output	Channel B Analog Output Voltage.
3	5	V _{OUTC}	Analog Output	Channel C Analog Output Voltage.
4	6	V _{OUTD}	Analog Output	Channel D Analog Output Voltage.
5	7	V _A	Supply	Power supply input. Must be decoupled to GND.
6	8	V _{REF1}	Analog Input	Unbuffered reference voltage shared by Channels A, B, C, and D. Must be decoupled to GND.
7	9	V _{REF2}	Analog Input	Unbuffered reference voltage shared by Channels E, F, G, and H. Must be decoupled to GND.
8	10	GND	Ground	Ground reference for all on-chip circuitry.
9	11	V _{OUTH}	Analog Output	Channel H Analog Output Voltage.
10	12	V _{OUTG}	Analog Output	Channel G Analog Output Voltage.
11	13	V _{OUTF}	Analog Output	Channel F Analog Output Voltage.
12	14	V _{OUTE}	Analog Output	Channel E Analog Output Voltage.
13	15	SYNC	Digital Input	Frame Synchronization Input. When this pin goes low, data is written into the DAC's input shift register on the falling edges of SCLK. After the 16th falling edge of SCLK, a rising edge of SYNC causes the DAC to be updated. If SYNC is brought high before the 15th falling edge of SCLK, the rising edge of SYNC acts as an interrupt and the write sequence is ignored by the DAC.
14	16	SCLK	Digital Input	Serial Clock Input. Data is clocked into the input shift register on the falling edges of this pin.
15	1	D _{IN}	Digital Input	Serial Data Input. Data is clocked into the 16-bit shift register on the falling edges of SCLK after the fall of SYNC.
16	2	D _{OUT}	Digital Output	Serial Data Output. D_{OUT} is utilized in daisy chain operation and is connected directly to a D_{IN} pin on another DAC088S085. Data is not available at D_{OUT} unless SYNC remains low for more than 16 SCLK cycles.

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Pin Descriptions (continued)

LLP Pin No.	TSSOP Pin No.	Symbol	Туре	Description
17		PAD (LLP only)	Ground	Exposed die attach pad can be connected to ground or left floating. Soldering the pad to the PCB offers optimal thermal performance and enhances package self-alignment during reflow.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1) (2)

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Supply Voltage, V _A	6.5V
Voltage on any Input Pin	-0.3V to 6.5V
Input Current at Any Pin (3)	10 mA
Package Input Current (3)	30 mA
Power Consumption at T _A = 25°C	See (4)
ESD Susceptibility ⁽⁵⁾ Human Body Model Machine Model Charge Device Mode	2500V 250V 1000V
Junction Temperature	+150°C
Storage Temperature	−65°C to +150°C

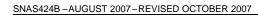
- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions. Operation of the device beyond the maximum Operating Ratings is not recommended.
- (2) All voltages are measured with respect to GND = 0V, unless otherwise specified.
- (3) When the input voltage at any pin exceeds 5.5V or is less than GND, the current at that pin should be limited to 10 mA. The 30 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 10 mA to three.
- (4) The absolute maximum junction temperature (T_Jmax) for this device is 150°C. The maximum allowable power dissipation is dictated by T_Jmax, the junction-to-ambient thermal resistance (θ_{JA}), and the ambient temperature (T_A), and can be calculated using the formula P_DMAX = (T_Jmax T_A) / θ_{JA}. The values for maximum power dissipation will be reached only when the device is operated in a severe fault condition (e.g., when input or output pins are driven beyond the operating ratings, or the power supply polarity is reversed). Such conditions should always be avoided.
- (5) Human body model is 100 pF capacitor discharged through a 1.5 kΩ resistor. Machine model is 220 pF discharged through 0 Ω. Charge device model simulates a pin slowly acquiring charge (such as from a device sliding down the feeder in an automated assembler) then rapidly being discharged.

Operating Ratings (1) (2)

Operating Temperature Range	-40 °C $\leq T_A \leq +125$ °C
Supply Voltage, V _A	+2.7V to 5.5V
Reference Voltage, V _{REF1,2}	+0.5V to V _A

⁽¹⁾ Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions. Operation of the device beyond the maximum Operating Ratings is not recommended.

All voltages are measured with respect to GND = 0V, unless otherwise specified.

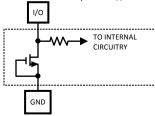




Operating Ratings (1) (2) (continued)

Digital Input Voltage (3)	0.0V to 5.5V
Output Load	0 to 1500 pF
SCLK Frequency	Up to 40 MHz

(3) The inputs are protected as shown below. Input voltage magnitudes up to 5.5V, regardless of V_A, will not cause errors in the conversion result. For example, if V_A is 3V, the digital input pins can be driven with a 5V logic device.



Package Thermal Resistances

Package	θ_{JA}
16-Lead LLP	38°C/W
16-Lead TSSOP	130°C/W



Electrical Characteristics

The following specifications apply for $V_A = +2.7V$ to +5.5V, $V_{REF1} = V_{REF2} = V_A$, $C_L = 200$ pF to GND, $f_{SCLK} = 30$ MHz, input code range 3 to 252. **Boldface limits apply for T_{MIN} \le T_A \le T_{MAX}** and all other limits are at $T_A = 25^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Conditions	Typical	Limits (1)	Units (Limits)
ATIC PERFO	RMANCE		1	1	1
	Resolution			8	Bits (min)
	Monotonicity			8	Bits (min)
INL	Integral Non- Linearity		±0.12	±0.5	LSB (max)
DNL	Differential Non-		+0.03	+0.15	LSB (max)
	Linearity		-0.02	-0.1	LSB (min)
ZE	Zero Code Error	I _{OUT} = 0	+5	+15	mV (max)
FSE	Full-Scale Error	$I_{OUT} = 0$	-0.1	-0.75	% FSR (ma
GE	Gain Error		-0.2	-1.0	% FSR (ma
ZCED	Zero Code Error Drift		-20		μV/°C
TC GE	Gain Error Tempco		-1.0		ppm/°C
TPUT CHAR	ACTERISTICS				
	Output Voltage Range			0 V _{REF1,2}	V (min) V (max)
l _{oz}	High-Impedance Output Leakage Current			±1	μA (max)
		V _A = 3V, I _{OUT} = 200 μA	10		mV
700	7 0 1 0	V _A = 3V, I _{OUT} = 1 mA	45		mV
ZCO	Zero Code Output	V _A = 5V, I _{OUT} = 200 μA	8		mV
		V _A = 5V, I _{OUT} = 1 mA	34		mV
		V _A = 3V, I _{OUT} = 200 μA	2.984		V
		V _A = 3V, I _{OUT} = 1 mA	2.933		V
FSO	Full Scale Output	V _A = 5V, I _{OUT} = 200 μA	4.987		V
		V _A = 5V, I _{OUT} = 1 mA	4.955		V
	Output Short	V _A = 3V, V _{OUT} = 0V, Input Code = FFh	-50		mA
I _{OS}	Circuit Current (source) (3)	V _A = 5V, V _{OUT} = 0V, Input Code = FFh	-60		mA
	Output Short	V _A = 3V, V _{OUT} = 3V, Input Code = 00h	50		mA
I _{OS}	Circuit Current (sink) (3)	V _A = 5V, V _{OUT} = 5V, Input Code = 00h	70		mA
	Continuous	T _A = 105°C		10	mA (max)
I _O	Output Current per channel (2)	T _A = 125°C		6.5	mA (max)
	Maximum Load	R _L = ∞	1500		pF
C_L	Capacitance	$R_L = 2k\Omega$	1500		pF
Z _{OUT}	DC Output Impedance		8		Ω

¹⁾ Test limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

⁽²⁾ This parameter is guaranteed by design and/or characterization and is not tested in production.

⁽³⁾ This parameter does not represent a condition which the DAC can sustain continuously. See the continuous output current specification for the maximum DAC output current per channel.



Electrical Characteristics (continued)

The following specifications apply for $V_A = +2.7V$ to +5.5V, $V_{REF1} = V_{REF2} = V_A$, $C_L = 200$ pF to GND, $f_{SCLK} = 30$ MHz, input code range 3 to 252. **Boldface limits apply for T_{MIN} \le T_A \le T_{MAX}** and all other limits are at $T_A = 25^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Cond	itions	Typical	Limits (1)	Units (Limits)	
	Input Range Minimum			0.5	2.7	V (min)	
VREF1,2	Input Range Maximum				V_{A}	V (max)	
	Input Impedance			30		kΩ	
GIC INPUT C	HARACTERISTICS						
I _{IN}	Input Current (2)				±1	μA (max)	
V_{IL}	Input Low Voltage	$V_A = 2.7V \text{ to } 3.6V$		1.0	0.6	V (max)	
۷IL	input Low voltage	$V_A = 4.5V \text{ to } 5.5V$		1.1	0.8	V (max)	
V_{IH}	Input High	$V_A = 2.7V \text{ to } 3.6V$		1.4	2.1	V (min)	
VIH	Voltage	$V_A = 4.5V \text{ to } 5.5V$		2.0	2.4	V (min)	
C_{IN}	Input Capacitance				3	pF (max)	
WER REQUIF	REMENTS	T					
V_{A}	Supply Voltage Minimum				2.7	V (min)	
V A	Supply Voltage Maximum				5.5	V (max)	
Normal Supply Current for supp pin V _A		f _{SCLK} = 30 MHz,	V _A = 2.7V to 3.6V	460	575	μA (max)	
	pin V _A	pin V _A	output unloaded	V _A = 4.5V to 5.5V	650	840	μA (max)
I _N Normal Supply	'N	Normal Supply Current for V _{REF1}	f _{SCLK} = 30 MHz,	V _A = 2.7V to 3.6V	95	135	μA (max)
	or V _{REF2}	output unloaded	V _A = 4.5V to 5.5V	160	225	μA (max)	
	Static Supply Current for supply	$f_{SCLK} = 0$,	V _A = 2.7V to 3.6V	370		μΑ	
lo-	pin V _A	output unloaded	V _A = 4.5V to 5.5V	440		μА	
I _{ST}	Static Supply Current for V _{REF1}	$f_{SCLK} = 0$,	V _A = 2.7V to 3.6V	95		μΑ	
	or V _{REF2}	output unloaded	V _A = 4.5V to 5.5V	160		μΑ	
		$f_{SCLK} = 30 \text{ MHz},$ SYNC = V_A and	V _A = 2.7V to 3.6V	0.2	1.5	μA (max)	
I _{PD}	Total Power Down Supply Current for	D _{IN} = 0V after PD mode loaded	V _A = 4.5V to 5.5V	0.5	3.0	μA (max)	
-FD	all PD Modes	$f_{SCLK} = 0$, SYNC = V_A and $D_{IN} = 0V$	V _A = 2.7V to 3.6V	0.1	1.0	μA (max)	
		after PD mode loaded	V _A = 4.5V to 5.5V	0.2	2.0	μA (max)	
Total Power P _N Consumption (output unloa	f _{SCLK} = 30 MHz		V _A = 2.7V to 3.6V	1.95	3.0	mW (max)	
		output unloaded	V _A = 4.5V to 5.5V	4.85	7.1	mW (max)	
	(output unloaded)	f _{SCLK} = 0	V _A = 2.7V to 3.6V	1.68		mW	
		output unloaded	$V_A = 4.5V$ to 5.5V	3.80		mW	

⁽⁴⁾ This parameter is guaranteed by design and/or characterization and is not tested in production.



Electrical Characteristics (continued)

The following specifications apply for $V_A = +2.7V$ to +5.5V, $V_{REF1} = V_{REF2} = V_A$, $C_L = 200$ pF to GND, $f_{SCLK} = 30$ MHz, input code range 3 to 252. **Boldface limits apply for T_{MIN} \le T_A \le T_{MAX}** and all other limits are at $T_A = 25^{\circ}C$, unless otherwise specified.

Symbol	Parameter	Conditions		Typical	Limits (1)	Units (Limits)	
	Total Power Consumption in all PD Modes,	$f_{SCLK} = 30 \text{ MHz},$ SYNC = V_A and	V _A = 2.7V to 3.6V	0.6	5.4	μW (max)	
Б		mode loaded	V _A = 4.5V to 5.5V	2.5	16.5	μW (max)	
P_{PD}			all PD Modes,	f _{SCLK} = 0, SYNC = V _A and D _{IN} = 0V	V _A = 2.7V to 3.6V	0.3	3.6
	after PD mode loaded	V _A = 4.5V to 5.5V	1	11	μW (max)		

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A.C. and Timing Characteristics

The following specifications apply for $V_A = +2.7 V$ to +5.5 V, $V_{REF1,2} = V_A$, $C_L = 200$ pF to GND, $f_{SCLK} = 30$ MHz, input code range 3 to 252. **Boldface limits apply for T_{MIN} \le T_A \le T_{MAX}** and all other limits are at $T_A = 25^{\circ} C$, unless otherwise specified.

Symbol	Parameter	Conductions	Typical	Limits (1)	Units (Limits)
f _{SCLK}	SCLK Frequency		40	30	MHz (max)
t _s	Output Voltage Settling Time	40h to C0h code change $R_L = 2k\Omega$, $C_L = 200 pF$	3	4.5	μs (max)
SR	Output Slew Rate		1		V/µs
GI	Glitch Impulse	Code change from 80h to 7Fh	40		nV-sec
DF	Digital Feedthrough		0.5		nV-sec
DC	Digital Crosstalk		0.5		nV-sec
CROSS	DAC-to-DAC Crosstalk		1		nV-sec
MBW	Multiplying Bandwidth	$V_{REF1,2} = 2.5V \pm 2Vpp$	360		kHz
ONSD	Output Noise Spectral Density	DAC Code = 80h, 10kHz	40		nV/sqrt(Hz)
ON	Output Noise	BW = 30kHz	14		μV
	Waka Un Tima	V _A = 3V	3		μsec
t _{WU}	Wake-Up Time	V _A = 5V	20		μsec
1/f _{SCLK}	SCLK Cycle Time		25	33	ns (min)
t _{CH}	SCLK High time		7	10	ns (min)
t _{CL}	SCLK Low Time		7	10	ns (min)
t _{SS}	SYNC Set-up Time prior to SCLK Falling Edge		3	10 1 / f _{SCLK} - 3	ns (min)
t _{DS}	Data Set-Up Time prior to SCLK Falling Edge		1.0	2.5	ns (min)
t _{DH}	Data Hold Time after SCLK Falling Edge		1.0	2.5	ns (min)
	SYNC Hold Time after the		0	3	ns (min)
t _{SH}	16th falling edge of SCLK			1 / f _{SCLK} - 3	ns (max)
t _{SYNC}	SYNC High Time		5	15	ns (min)

Test limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

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This parameter is guaranteed by design and/or characterization and is not tested in production.



Timing Diagrams

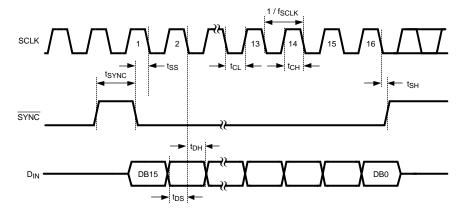


Figure 1. Serial Timing Diagram

Specification Definitions

DIFFERENTIAL NON-LINEARITY (DNL) is the measure of the maximum deviation from the ideal step size of 1 LSB, which is $V_{RFF} / 256 = V_A / 256$.

DAC-to-DAC CROSSTALK is the glitch impulse transferred to a DAC output in response to a full-scale change in the output of another DAC.

DIGITAL CROSSTALK is the glitch impulse transferred to a DAC output at mid-scale in response to a full-scale change in the input register of another DAC.

DIGITAL FEEDTHROUGH is a measure of the energy injected into the analog output of the DAC from the digital inputs when the DAC outputs are not updated. It is measured with a full-scale code change on the data bus.

FULL-SCALE ERROR is the difference between the actual output voltage with a full scale code (FFh) loaded into the DAC and the value of V_A x 255 / 256.

GAIN ERROR is the deviation from the ideal slope of the transfer function. It can be calculated from Zero and Full-Scale Errors as GE = FSE - ZE, where GE is Gain error, FSE is Full-Scale Error and ZE is Zero Error.

GLITCH IMPULSE is the energy injected into the analog output when the input code to the DAC register changes. It is specified as the area of the glitch in nanovolt-seconds.

INTEGRAL NON-LINEARITY (INL) is a measure of the deviation of each individual code from a straight line through the input to output transfer function. The deviation of any given code from this straight line is measured from the center of that code value. The end point method is used. INL for this product is specified over a limited range, per the Electrical Tables.

LEAST SIGNIFICANT BIT (LSB) is the bit that has the smallest value or weight of all bits in a word. This value is $LSB = V_{REF} / 2^n$ (1)

where V_{REF} is the supply voltage for this product, and "n" is the DAC resolution in bits, which is 8 for the DAC088S085.

MAXIMUM LOAD CAPACITANCE is the maximum capacitance that can be driven by the DAC with output stability maintained.

MONOTONICITY is the condition of being monotonic, where the DAC has an output that never decreases when the input code increases.

MOST SIGNIFICANT BIT (MSB) is the bit that has the largest value or weight of all bits in a word. Its value is 1/2 of V_A .



MULTIPLYING BANDWIDTH is the frequency at which the output amplitude falls 3dB below the input sine wave on V_{REF1.2} with the DAC code at full-scale.

NOISE SPECTRAL DENSITY is the internally generated random noise. It is measured by loading the DAC to mid-scale and measuring the noise at the output.

POWER EFFICIENCY is the ratio of the output current to the total supply current. The output current comes from the power supply. The difference between the supply and output currents is the power consumed by the device without a load.

SETTLING TIME is the time for the output to settle to within 1/2 LSB of the final value after the input code is updated.

TOTAL HARMONIC DISTORTION PLUS NOISE (THD+N) is the ratio of the harmonics plus the noise present at the output of the DACs to the rms level of an ideal sine wave applied to V_{REF1.2} with the DAC code at mid-scale.

WAKE-UP TIME is the time for the output to exit power-down mode. This is the time from the rising edge of SYNC to when the output voltage deviates from the power-down voltage of 0V.

ZERO CODE ERROR is the output error, or voltage, present at the DAC output after a code of 00h has been entered.

Transfer Characteristic

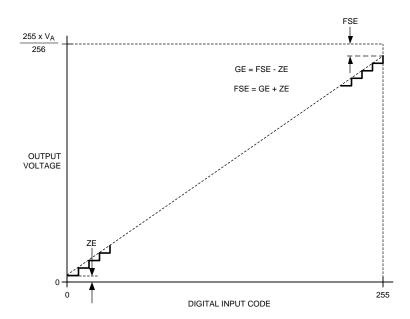
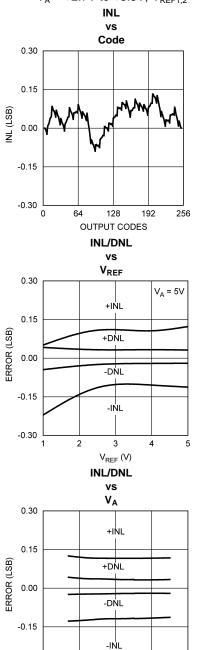


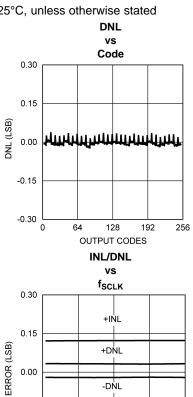
Figure 2. Input / Output Transfer Characteristic



Typical Performance Characteristics

 V_A = +2.7V to +5.5V, $V_{REF1,2}$ = V_A , f_{SCLK} = 30 MHz, T_A = 25°C, unless otherwise stated





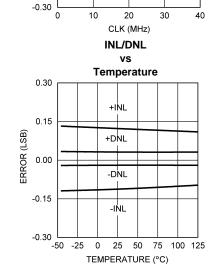
+DNL

-DNL

-INL

0.00

-0.15



-0.30

3

4

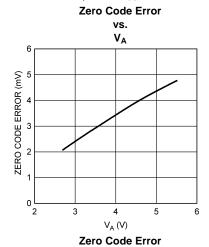
 $V_A(V)$

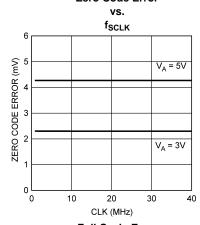
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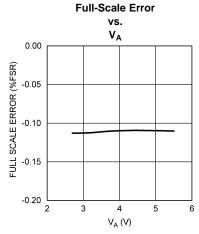


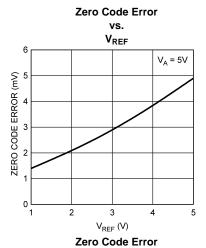
Typical Performance Characteristics (continued)

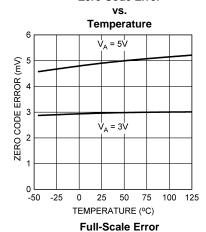
 V_A = +2.7V to +5.5V, $V_{REF1,2}$ = V_A , f_{SCLK} = 30 MHz, T_A = 25°C, unless otherwise stated

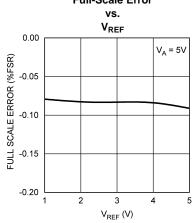








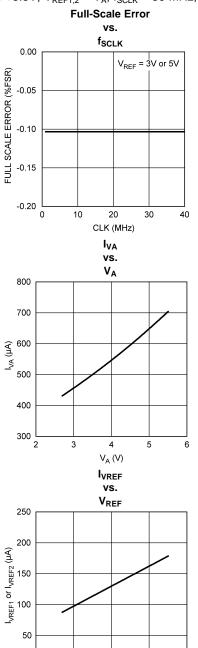


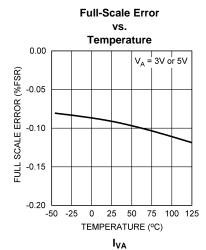


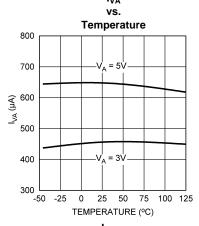


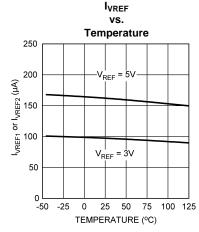
Typical Performance Characteristics (continued)

 V_A = +2.7V to +5.5V, $V_{REF1,2}$ = V_A , f_{SCLK} = 30 MHz, T_A = 25°C, unless otherwise stated









0 L 2

5

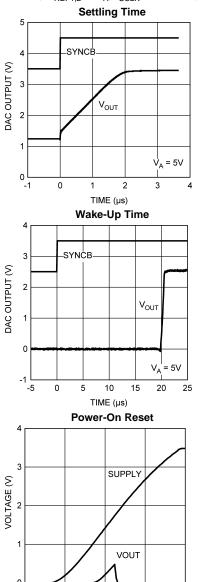
 $V_{REF}(V)$

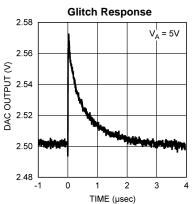
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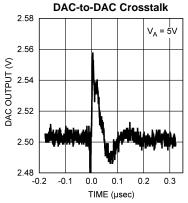


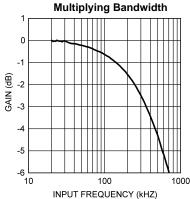
Typical Performance Characteristics (continued)

 $V_A = +2.7V$ to +5.5V, $V_{REF1,2} = V_A$, $f_{SCLK} = 30$ MHz, $T_A = 25$ °C, unless otherwise stated









Functional Description

0.0

2.5

5.0

TIME (msec)

7.5

10.0

DAC ARCHITECTURE

The DAC088S085 is fabricated on a CMOS process with an architecture that consists of switches and resistor strings that are followed by an output buffer. The reference voltages are externally applied at V_{REF1} for DAC channels A through D and V_{REF2} for DAC channels E through H.

For simplicity, a single resistor string is shown in Figure 3. This string consists of 256 equal valued resistors with a switch at each junction of two resistors, plus a switch to ground. The code loaded into the DAC register determines which switch is closed, connecting the proper node to the amplifier. The input coding is straight binary with an ideal output voltage of:

$$V_{OUTA,B,C,D} = V_{REF1} \times (D / 256)$$

$$V_{OUTE,F,G,H} = V_{REF2} \times (D / 256)$$
 (3)



where D is the decimal equivalent of the binary code that is loaded into the DAC register. D can take on any value between 0 and 255. This configuration guarantees that the DAC is monotonic.

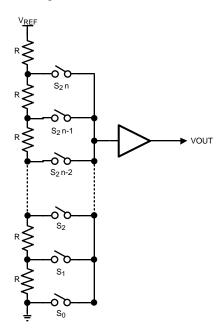


Figure 3. DAC Resistor String

Since all eight DAC channels of the DAC088S085 can be controlled independently, each channel consists of a DAC register and a 8-bit DAC. Figure 4 is a simple block diagram of an individual channel in the DAC088S085. Depending on the mode of operation, data written into a DAC register causes the 8-bit DAC output to be updated or an additional command is required to update the DAC output. Further description of the modes of operation can be found in the Serial Interface description.

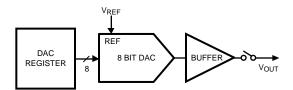


Figure 4. Single Channel Block Diagram

OUTPUT AMPLIFIERS

The output amplifiers are rail-to-rail, providing an output voltage range of 0V to VA when the reference is VA. All amplifiers, even rail-to-rail types, exhibit a loss of linearity as the output approaches the supply rails (0V and VA) in this case). For this reason, linearity is specified over less than the full output range of the DAC. However, if the reference is less than V_A, there is only a loss in linearity in the lowest codes.

The output amplifiers are capable of driving a load of 2 kΩ in parallel with 1500 pF to ground or to V_A. The zerocode and full-scale outputs for given load currents are available in the Electrical Characteristics Table.

REFERENCE VOLTAGE

The DAC088S085 uses dual external references, V_{REF1} and V_{REF2} , that are shared by channels A, B, C, D and channels E, F, G, H respectively. The reference pins are not buffered and have an input impedance of 30 kΩ. It is recommended that V_{REF1} and V_{REF2} be driven by voltage sources with low output impedance. The reference voltage range is 0.5V to V_A, providing the widest possible output dynamic range.



SERIAL INTERFACE

The three-wire interface is compatible with SPI™, QSPI and MICROWIRE, as well as most DSPs and operates at clock rates up to 40 MHz. A valid serial frame contains 16 falling edges of SCLK. See Figure 1 for information on a write sequence.

A write sequence begins by bringing the \overline{SYNC} line low. Once \overline{SYNC} is low, the data on the D_{IN} line is clocked into the 16-bit serial input register on the falling edges of SCLK. To avoid mis-clocking data into the shift register, it is critical that \overline{SYNC} not be brought low on a falling edge of SCLK (see minimum and maximum setup times for \overline{SYNC} in the Timing Characteristics and Figure 5). On the 16th falling edge of SCLK, the last data bit is clocked into the register. The write sequence is concluded by bringing the \overline{SYNC} line high. Once \overline{SYNC} is high, the programmed function (a change in the DAC channel address, mode of operation and/or register contents) is executed. To avoid mis-clocking data into the shift register, it is critical that \overline{SYNC} be brought high between the 16th and 17th falling edges of SCLK (see minimum and maximum hold times for \overline{SYNC} in the Timing Characteristics and Figure 5).

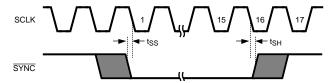


Figure 5. CS Setup and Hold Times

If SYNC is brought high before the 15th falling edge of SCLK, the write sequence is aborted and the data that has been shifted into the input register is discarded. If SYNC is held low beyond the 17th falling edge of SCLK, the serial data presented at D_{IN} will begin to be output on D_{OUT}. More information on this mode of operation can be found in the DAISY CHAIN OPERATION section. In either case, SYNC must be brought high for the minimum specified time before the next write sequence is initiated with a falling edge of SYNC.

Since the D_{IN} buffer draws more current when it is high, it should be idled low between write sequences to minimize power consumption. On the other hand, \overline{SYNC} should be idled high to avoid the activation of daisy chain operation where D_{OUT} is active.

DAISY CHAIN OPERATION

Daisy chain operation allows communication with any number of DAC088S085s using a single serial interface. As long as the correct number of data bits are input in a write sequence (multiple of sixteen bits), a rising edge of SYNC will properly update all DACs in the system.

To support multiple devices in a daisy chain configuration, SCLK and $\overline{\text{SYNC}}$ are shared across all DAC088S085s and D_{OUT} of the first DAC in the chain is connected to D_{IN} of the second. Figure 6 shows three DAC088S085s connected in daisy chain fashion. Similar to a single channel write sequence, the conversion for a daisy chain operation begins on a falling edge of $\overline{\text{SYNC}}$ and ends on a rising edge of $\overline{\text{SYNC}}$. A valid write sequence for n devices in a chain requires n times 16 falling edges to shift the entire input data stream through the chain. Daisy chain operation is guaranteed for a maximum SCLK speed of 30MHz.

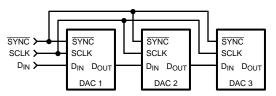


Figure 6. Daisy Chain Configuration

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The serial data output pin, D_{OUT} , is available on the DAC088S085 to allow daisy-chaining of multiple DAC088S085 devices in a system. In a write sequence, D_{OUT} remains low for the first fourteen falling edges of SCLK before going high on the fifteenth falling edge. Subsequently, the next sixteen falling edges of SCLK will output the first sixteen data bits entered into D_{IN} . Figure 7 shows the timing of three DAC088S085s in Figure 6. In this instance, It takes forty-eight falling edges of SCLK followed by a rising edge of SYNC to load all three DAC088S085s with the appropriate register data. On the rising edge of SYNC, the programmed function is executed in each DAC088S085 simultaneously.

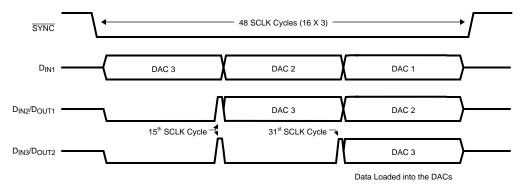


Figure 7. Daisy Chain Timing Diagram

SERIAL INPUT REGISTER

The DAC088S085 has two modes of operation plus a few special command operations. The two modes of operation are Write Register Mode (WRM) and Write Through Mode (WTM). For the rest of this document, these modes will be referred to as WRM and WTM. The special command operations are separate from WRM and WTM because they can be called upon regardless of the current mode of operation. The mode of operation is controlled by the first four bits of the control register, DB15 through DB12. See Table 2 for a detailed summary.

Table 2. Write Register and Write Through Modes

DB[15:12]	DB[11:0]	Description of Mode
1000	XXXXXXXXXX	WRM: The registers of each DAC Channel can be written to without causing their outputs to change.
1 0 0 1	$\times \times $	WTM: Writing data to a channel's register causes the DAC output to change.

When the DAC088S085 first powers up, the DAC is in WRM. In WRM, the registers of each individual DAC channel can be written to without causing the DAC outputs to be updated. This is accomplished by setting DB15 to "0", specifying the DAC register to be written to in DB[14:12], and entering the new DAC register setting in DB[11:0] (see Table 3). The DAC088S085 remains in WRM until the mode of operation is changed to WTM. The mode of operation is changed from WRM to WTM by setting DB[15:12] to "1001". Once in WTM, writing data to a DAC channel's register causes the DAC's output to be updated as well. Changing a DAC channel's register in WTM is accomplished in the same manner as it is done in WRM. However, in WTM the DAC's register and output are updated at the completion of the command (see Table 3). Similarly, the DAC088S085 remains in WTM until the mode of operation is changed to WRM by setting DB[15:12] to "1000".

Table 3. Commands Impacted by WRM and WTM

DB15	DB[14:12]	DB[11:0]	Description of Mode
0	0 0 0	D11 D10 D4 X X X X	WRM: D[11:0] written to ChA's data register only WTM: ChA's output is updated by data in D[11:0]
0	0 0 1	D11 D10 D4 X X X X	WRM: D[11:0] written to ChB's data register only WTM: ChB's output is updated by data in D[11:0]
0	0 1 0	D11 D10 D4 X X X X	WRM: D[11:0] written to ChC's data register only WTM: ChC's output is updated by data in D[11:0]
0	0 1 1	D11 D10 D4 X X X X	WRM: D[11:0] written to ChD's data register only WTM: ChD's output is updated by data in D[11:0]



Table 3. Commands Impacted by WRM and WTM (continued)

0	1 0 0	D11 D10 D4 X X X X	WRM: D[11:0] written to ChE's data register only WTM: ChE's output is updated by data in D[11:0]
0	1 0 1	D11 D10 D4 X X X X	WRM: D[11:0] written to ChF's data register only WTM: ChF's output is updated by data in D[11:0]
0	1 1 0	D11 D10 D4 X X X X	WRM: D[11:0] written to ChG's data register only WTM: ChG's output is updated by data in D[11:0]
0	1 1 1	D11 D10 D4 X X X X	WRM: D[11:0] written to ChH's data register only WTM: ChH's output is updated by data in D[11:0]

As mentioned previously, the special command operations can be exercised at any time regardless of the mode of operation. There are three special command operations. The first command is exercised by setting data bits DB[15:12] to "1010". This allows a user to update multiple DAC outputs simultaneously to the values currently loaded in their respective control registers. This command is valuable if the user wants each DAC output to be at a different output voltage but still have all the DAC outputs change to their appropriate values simultaneously (see Table 4).

The second special command allows the user to alter the DAC output of channel A with a single write frame. This command is exercised by setting data bits DB[15:12] to "1011" and data bits DB[11:0] to the desired control register value. It also has the added benefit of causing the DAC outputs of the other channels to update to their current control register values as well. A user may choose to exercise this command to save a write sequence. For example, the user may wish to update several DAC outputs simultaneously, including channel A. In order to accomplish this task in the minimum number of write frames, the user would alter the control register values of all the DAC channels except channel A while operating in WRM. The last write frame would be used to exercise the special command "Channel A Write Mode". In addition to updating channel A's control register and output to a new value, all of the other channels would be updated as well. At the end of this sequence of write frames, the DAC088S085 would still be operating in WRM (see Table 4).

The third special command allows the user to set all the DAC control registers and outputs to the same level. This command is commonly referred to as "broadcast" mode since the same data bits are being broadcast to all of the channels simultaneously. This command is exercised by setting data bits DB[15:12] to "1100" and data bits DB[7:0] to the value that the user wishes to broadcast to all the DAC control registers. Once the command is exercised, each DAC output is updated by the new control register value. This command is frequently used to set all the DAC outputs to some known voltage such as 0V, V_{REF}/2, or Full Scale. A summary of the commands can be found in Table 4.

Table 4. Special Command Operations

DB[15:12]	DB[11:0]	Description of Mode
1010	XXXXHGFEDCBA	Update Select: The DAC outputs of the channels selected with a "1" in DB[7:0] are updated simultaneously to the values in their respective control registers.
1 0 1 1	D11 D10 D4 X X X X	Channel A Write: Channel A's control register and DAC output are updated to the data in DB[11:0]. The outputs of the other seven channels are also updated according to their respective control register values.
1100	D11 D10 D4 X X X X	Broadcast: The data in DB[11:0] is written to all channels' control register and DAC output simultaneously.

POWER-ON RESET

The power-on reset circuit controls the output voltages of the eight DACs during power-up. Upon application of power, the DAC registers are filled with zeros and the output voltages are set to 0V. The outputs remain at 0V until a valid write sequence is made.

POWER-DOWN MODES

The DAC088S085 has three power-down modes where different output terminations can be selected (see Table 5). With all channels powered down, the supply current drops to 0.1 μ A at 3V and 0.2 μ A at 5V. By selecting the channels to be powered down in DB[7:0] with a "1", individual channels can be powered down separately or multiple channels can be powered down simultaneously. The three different output terminations include high output impedance, 100k ohm to ground, and 2.5k ohm to ground.



The output amplifiers, resistor strings, and other linear circuitry are all shut down in any of the power-down modes. The bias generator, however, is only shut down if all the channels are placed in power-down mode. The contents of the DAC registers are unaffected when in power-down. Therefore, each DAC register maintains its value prior to the DAC088S085 being powered down unless it is changed during the write sequence which instructed it to recover from power down. Minimum power consumption is achieved in the power-down mode with SYNC idled high, D_{IN} idled low, and SCLK disabled. The time to exit power-down (Wake-Up Time) is typically 3 µsec at 3V and 20 µsec at 5V.

Table 5. Power-Down Modes

DB[15:12]	DB[11:8]	7	6	5	4	3	2	1	0	Output Impedance
1 1 0 1	XXXX	Н	G	F	Е	D	С	В	Α	High-Z outputs
1110	XXXX	Н	G	F	Е	D	С	В	Α	100 kΩ outputs
1111	XXXX	Н	G	F	Е	D	С	В	Α	2.5 kΩ outputs

Applications Information

EXAMPLES PROGRAMMING THE DAC088S085

This section will present the step-by-step instructions for programming the serial input register.

Updating DAC Outputs Simultaneously

When the DAC088S085 is first powered on, the DAC is operating in Write Register Mode (WRM). Operating in WRM allows the user to program the registers of multiple DAC channels without causing the DAC outputs to be updated. As an example, here are the steps for setting Channel A to a full scale output, Channel B to three-quarters full scale, Channel C to half-scale, Channel D to one-quarter full scale and having all the DAC outputs update simultaneously.

As stated previously, the DAC088S085 powers up in WRM. If the device was previously operating in Write Through Mode (WTM), an extra step to set the DAC into WRM would be required. First, the DAC registers need to be programmed to the desired values. To set Channel A to an output of full scale, write "0FF0" to the control register. This will update the data register for Channel A without updating the output of Channel A. Second, set Channel B to an output of three-quarters full scale by writing "1C00" to the control register. This will update the data register for Channel B. Once again, the output of Channel B and Channel A will not be updated since the DAC is operating in WRM. Third, set Channel C to half scale by writing "2800" to the control register. Fourth, set Channel D to one-quarter full scale by writing "3400" to the control register. Finally, update all four DAC channels simultaneously by writing "A00F" to the control register. This procedure allows the user to update four channels simultaneously with five steps.

Since Channel A was one of the DACs to be updated, one command step could have been saved by writing to Channel A last. This is accomplished by writing to Channel B, C, and D first and using the special command "Channel A Write" to update Channel A's DAC register and output. This special command has the added benefit of updating all DAC outputs while updating Channel A. With this sequence of commands, the user was able to update four channels simultaneously with four steps. A summary of this command can be found in Table 4.

Updating DAC Outputs Independently

If the DAC088S085 is currently operating in WRM, change the mode of operation to WTM by writing "9XXX" to the control register. Once the DAC is operating in WTM, any DAC channel can be updated in one step. For example, if a design required Channel G to be set to half scale, the user can write "6800" to the control register and Channel G's data register and DAC output will be updated. Similarly, if Channel F's output needed to be set to full scale, "5FF0" would need to be written to the control register. Channel A is the only channel that has a special command that allows its DAC output to be updated in one command regardless of the mode of operation. Setting Channel A's DAC output to full scale could be accomplished in one step by writing "BFFF" to the control register.



USING REFERENCES AS POWER SUPPLIES

While the simplicity of the DAC088S085 implies ease of use, it is important to recognize that the path from the reference input ($V_{REF1,2}$) to the DAC outputs will have zero Power Supply Rejection Ratio (PSRR). Therefore, it is necessary to provide a noise-free supply voltage to $V_{REF1,2}$. In order to utilize the full dynamic range of the DAC088S085, the supply pin (V_A) and $V_{REF1,2}$ can be connected together and share the same supply voltage. Since the DAC088S085 consumes very little power, a reference source may be used as the reference input and/or the supply voltage. The advantages of using a reference source over a voltage regulator are accuracy and stability. Some low noise regulators can also be used. Listed below are a few reference and power supply options for the DAC088S085.

LM4132

The LM4132, with its $\pm 0.05\%$ accuracy over temperature, is a good choice as a reference source for the DAC088S085. The 4.096V version is useful if a 0V to 4.095V output range is desirable. Bypassing the LM4132 voltage input pin with a $4.7\mu F$ capacitor and the voltage output pin with a $4.7\mu F$ capacitor will improve stability and reduce output noise. The LM4132 comes in a space-saving 5-pin SOT23.

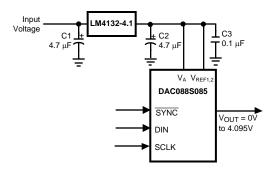


Figure 8. The LM4132 as a power supply

LM4050

Available with accuracy of ±0.1%, the LM4050 shunt reference is also a good choice as a reference for the DAC088S085. It is available in 4.096V and 5V versions and comes in a space-saving 3-pin SOT23.

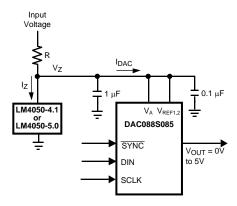


Figure 9. The LM4050 as a power supply

The minimum resistor value in the circuit of Figure 9 must be chosen such that the maximum current through the LM4050 does not exceed its 15 mA rating. The conditions for maximum current include the input voltage at its maximum, the LM4050 voltage at its minimum, and the DAC088S085 drawing zero current. The maximum resistor value must allow the LM4050 to draw more than its minimum current for regulation plus the maximum DAC088S085 current in full operation. The conditions for minimum current include the input voltage at its minimum, the LM4050 voltage at its maximum, the resistor value at its maximum due to tolerance, and the DAC088S085 draws its maximum current. These conditions can be summarized as

 $R(\min) = (V_{IN}(\max) - V_{Z}(\min)) / I_{Z}(\max)$ $\tag{4}$



and

$$R(max) = (V_{IN}(min) - V_{Z}(max)) / ((I_{DAC}(max) + I_{Z}(min))$$
(5)

where $V_Z(min)$ and $V_Z(max)$ are the nominal LM4050 output voltages \pm the LM4050 output tolerance over temperature, I₇(max) is the maximum allowable current through the LM4050, I₇(min) is the minimum current required by the LM4050 for proper regulation, and I_{DAC}(max) is the maximum DAC088S085 supply current.

LP3985

The LP3985 is a low noise, ultra low dropout voltage regulator with a ±3% accuracy over temperature. It is a good choice for applications that do not require a precision reference for the DAC088S085. It comes in 3.0V, 3.3V and 5V versions, among others, and sports a low 30 µV noise specification at low frequencies. Since low frequency noise is relatively difficult to filter, this specification could be important for some applications. The LP3985 comes in a space-saving 5-pin SOT23 and 5-bump micro SMD packages.

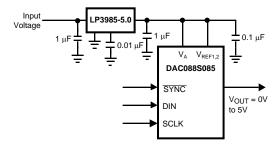


Figure 10. Using the LP3985 regulator

An input capacitance of 1.0µF without any ESR requirement is required at the LP3985 input, while a 1.0µF ceramic capacitor with an ESR requirement of $5m\Omega$ to $500m\Omega$ is required at the output. Careful interpretation and understanding of the capacitor specification is required to ensure correct device operation.

LP2980

The LP2980 is an ultra low dropout regulator with a ±0.5% or ±1.0% accuracy over temperature, depending upon grade. It is available in 3.0V, 3.3V and 5V versions, among others.

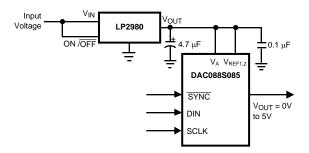


Figure 11. Using the LP2980 regulator

Like any low dropout regulator, the LP2980 requires an output capacitor for loop stability. This output capacitor must be at least 1.0µF over temperature, but values of 2.2µF or more will provide even better performance. The ESR of this capacitor should be within the range specified in the LP2980 data sheet. Surface-mount solid tantalum capacitors offer a good combination of small size and low ESR. Ceramic capacitors are attractive due to their small size but generally have ESR values that are too low for use with the LP2980. Aluminum electrolytic capacitors are typically not a good choice due to their large size and high ESR values at low temperatures.

BIPOLAR OPERATION

The DAC088S085 is designed for single supply operation and thus has a unipolar output. However, a bipolar output may be achieved with the circuit in Figure 12. This circuit will provide an output voltage range of ±5 Volts. A rail-to-rail amplifier should be used if the amplifier supplies are limited to ±5V.

Product Folder Links: DAC088S085



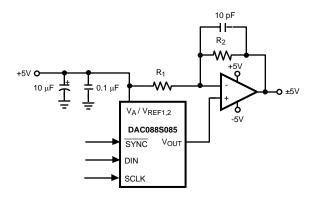


Figure 12. Bipolar Operation

The output voltage of this circuit for any code is found to be

$$V_{O} = (V_{A} \times (D / 256) \times ((R1 + R2) / R1) - V_{A} \times R2 / R1)$$
(6)

where D is the input code in decimal form. With $V_A = 5V$ and R1 = R2,

$$V_0 = (10 \times D / 256) - 5V$$
 (7)

A list of rail-to-rail amplifiers suitable for this application are indicated in Table 6.

Table 6. Some Rail-to-Rail Amplifiers

AMP	PKGS	Typ V _{OS}	Typ I _{SUPPLY}
LMP7701	SOT23-5	±37 μV	0.79 mA
LMV841	SOT23-5	−17 µV	1.11 mA
LMC7111	SOT23-5	900 μV	25 μΑ
LM7301	SOT23-5	30 μV	620 µA
LM8261	SOT23-5	700 μV	1 mA

VARIABLE CURRENT SOURCE OUTPUT

The DAC088S085 is a voltage output DAC but can be easily converted to a current output with the addition of an opamp. In Figure 13, one of the channels of the DAC088S085 is converted to a variable current source capable of sourcing up to 40mA.

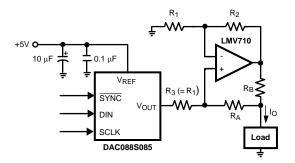


Figure 13. Variable Current Source

The output current of this circuit (I_{O}) for any DAC code is found to be

$$I_{O} = (V_{REF} \times (D / 256) \times (R_{2}) / (R_{1} \times R_{B})$$
 (8)

where D is the input code in decimal form and $R_2 = R_A + R_B$.



APPLICATION CIRCUITS

The following figures are examples of the DAC088S085 in typical application circuits. These circuits are basic and will generally require modification for specific circumstances.

Industrial Application

Figure 14 shows the DAC088S085 controlling several different circuits in an industrial setting. Channel A is shown providing the reference voltage to the ADC081S625, one of National Semiconductor's general purpose Analog-to-Digital Converters (ADCs). The reference for the ADC121S625 may be set to any voltage from 0.2V to 5.5V, providing the widest dynamic range possible. Typically, the ADC121S625 will be monitoring a sensor and would benefit from the ADC's reference voltage being adjustable. Channel B is providing the drive or supply voltage for a sensor. By having the sensor supply voltage adjustable, the output of the sensor can be optimized to the input level of the ADC monitoring it. Channel C is defined to adjust the offset or gain of an amplifier stage in the system. Channel D is configured with an opamp to provide an adjustable current source. Being able to convert one of the eight channels of the DAC088S085 to a current output eliminates the need for a separate current output DAC to be added to the circuit. Channel E, in conjunction with an opamp, provides a bipolar output swing for devices requiring control voltages that are centered around ground. Channel F and G are used to set the upper and lower limits for a range detector. Channel H is reserved for providing voltage control or acting as a voltage setpoint.

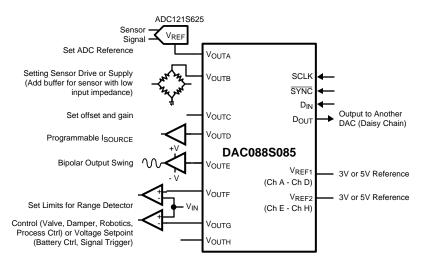


Figure 14. Industrial Application

ADC Reference

Figure 15 shows Channel A of the DAC088S085 providing the drive or supply voltage for a bridge sensor. By having the sensor supply voltage adjustable, the output of the sensor can be optimized to the input level of the ADC monitoring it. The output of the sensor is amplified by a fixed gain amplifier stage with a differential gain of 1 + 2 × (R_F / R_I). The advantage of this amplifier configuration is the high input impedance seen by the output of the bridge sensor. The disadvantage is the poor common-mode rejection ratio (CMRR). The common-mode voltage (V_{CM}) of the bridge sensor is half of Channel A's DAC output. The V_{CM} is amplified by a gain of 1V/V by the amplifier stage and thus becomes the bias voltage for the input of the ADC121S705. Channel B of the DAC088S085 is providing the reference voltage to the ADC121S705. The reference for the ADC121S705 may be set to any voltage from 1V to 5V, providing the widest dynamic range possible.

The reference voltage for Channel A and B is powered by an external 5V power supply. Since the 5V supply is common to the sensor supply voltage and the reference voltage of the ADC, fluctuations in the value of the 5V supply will have a minimal effect on the digital output code of the ADC. This type of configuration is often referred to as a "Ratio-metric" design. For example, an increase of 5% to the 5V supply will cause the sensor supply voltage to increase by 5%. This causes the gain or sensitivity of the sensor to increase by 5%. The gain of the amplifier stage is unaffected by the change in supply voltage. The ADC121S705 on the other hand, also

Product Folder Links: DAC088S085



experiences a 5% increase to its reference voltage. This causes the size of the ADC's least significant bit (LSB) to increase by 5%. As a result of the sensor's gain increasing by 5% and the LSB size of the ADC increasing by the same 5%, there is no net effect on the circuit's performance. It is assumed that the amplifier gain is set low enough to allow for a 5% increase in the sensor output. Otherwise, the increase in the sensor output level may cause the output of the amplifiers to clip.

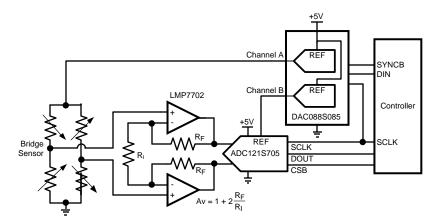


Figure 15. Driving an ADC Reference

Programmable Attenuator

Figure 16 shows one of the channels of the DAC088S085 being used as a single-quadrant multiplier. In this configuration, an AC or DC signal can be driven into one of the reference pins. The SPI interface of the DAC can be used to digitally attenuate the signal to any level from 0dB (full scale) to 0V. This is accomplished without adding any noticeable level of noise to the signal. An amplifier stage is shown in Figure 16 as a reference for applications where the input signal requires amplification. Note how the AC signal in this application is accoupled to the amplifier before being amplified. A separate bias voltage is used to set the common-mode voltage for the DAC088S085's reference input to $V_{\rm A}$ / 2, allowing the largest possible input swing. The multiplying bandwidth of $V_{\rm REF1,2}$ is 360kHz with a $V_{\rm CM}$ of 2.5V and a peak-to-peak signal swing of 2V.

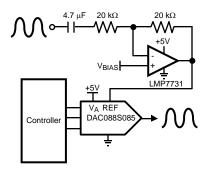


Figure 16. Programmable Attenuator

DSP/MICROPROCESSOR INTERFACING

Interfacing the DAC088S085 to microprocessors and DSPs is quite simple. The following guidelines are offered to hasten the design process.

ADSP-2101/ADSP2103 Interfacing

Figure 17 shows a serial interface between the DAC088S085 and the ADSP-2101/ADSP2103. The DSP should be set to operate in the SPORT Transmit Alternate Framing Mode. It is programmed through the SPORT control register and should be configured for Internal Clock Operation, Active Low Framing and 16-bit Word Length. Transmission is started by writing a word to the Tx register after the SPORT mode has been enabled.



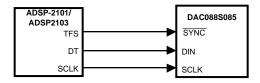


Figure 17. ADSP-2101/2103 Interface

80C51/80L51 Interface

A serial interface between the DAC088S085 and the 80C51/80L51 microcontroller is shown in Figure 18. The SYNC signal comes from a bit-programmable pin on the microcontroller. The example shown here uses port line P3.3. This line is taken low when data is transmitted to the DAC088S085. Since the 80C51/80L51 transmits 8-bit bytes, only eight falling clock edges occur in the transmit cycle. To load data into the DAC, the P3.3 line must be left low after the first eight bits are transmitted. A second write cycle is initiated to transmit the second byte of data, after which port line P3.3 is brought high. The 80C51/80L51 transmit routine must recognize that the 80C51/80L51 transmits data with the LSB first while the DAC088S085 requires data with the MSB first.

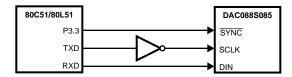


Figure 18. 80C51/80L51 Interface

68HC11 Interface

A serial interface between the DAC088S085 and the 68HC11 microcontroller is shown in Figure 19. The SYNC line of the DAC088S085 is driven from a port line (PC7 in the figure), similar to the 80C51/80L51.

The 68HC11 should be configured with its CPOL bit as a zero and its CPHA bit as a one. This configuration causes data on the MOSI output to be valid on the falling edge of SCLK. PC7 is taken low to transmit data to the DAC. The 68HC11 transmits data in 8-bit bytes with eight falling clock edges. Data is transmitted with the MSB first. PC7 must remain low after the first eight bits are transferred. A second write cycle is initiated to transmit the second byte of data to the DAC, after which PC7 should be raised to end the write sequence.

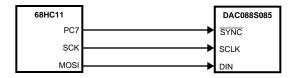


Figure 19. 68HC11 Interface

Microwire Interface

Figure 20 shows an interface between a Microwire compatible device and the DAC088S085. Data is clocked out on the rising edges of the SK signal. As a result, the SK of the Microwire device needs to be inverted before driving the SCLK of the DAC088S085.

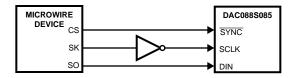


Figure 20. Microwire Interface



LAYOUT, GROUNDING, AND BYPASSING

For best accuracy and minimum noise, the printed circuit board containing the DAC088S085 should have separate analog and digital areas. The areas are defined by the locations of the analog and digital power planes. Both of these planes should be located in the same board layer. A single ground plane is preferred if digital return current does not flow through the analog ground area. Frequently a single ground plane design will utilize a "fencing" technique to prevent the mixing of analog and digital ground current. Separate ground planes should only be utilized when the fencing technique is inadequate. The separate ground planes must be connected in one place, preferably near the DAC088S085. Special care is required to guarantee that digital signals with fast edge rates do not pass over split ground planes. They must always have a continuous return path below their traces.

For best performance, the DAC088S085 power supply should be bypassed with at least a $1\mu F$ and a $0.1\mu F$ capacitor. The $0.1\mu F$ capacitor needs to be placed right at the device supply pin. The $1\mu F$ or larger valued capacitor can be a tantalum capacitor while the $0.1\mu F$ capacitor needs to be a ceramic capacitor with low ESL and low ESR. If a ceramic capacitor with low ESL and low ESR is used for the $1\mu F$ value and it can be placed right at the supply pin, the $0.1\mu F$ capacitor can be eliminated. Capacitors of this nature typically span the same frequency spectrum as the $0.1\mu F$ capacitor and thus eliminate the need for the extra capacitor. The power supply for the DAC088S085 should only be used for analog circuits.

It is also advisable to avoid the crossover of analog and digital signals. This helps minimize the amount of noise from the transitions of the digital signals from coupling onto the sensitive analog signals such as the reference pins and the DAC outputs.

Submit Documentation Feedback

PACKAGE OPTION ADDENDUM



17-Nov-2012

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Samples
	(1)		Drawing			(2)		(3)	(Requires Login)
DAC088S085CIMT	ACTIVE	TSSOP	PW	16	92	TBD	CU SNPB	Level-1-260C-UNLIM	
DAC088S085CIMT/NOPB	ACTIVE	TSSOP	PW	16	92	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
DAC088S085CIMTX	ACTIVE	TSSOP	PW	16	2500	TBD	CU SNPB	Level-1-260C-UNLIM	
DAC088S085CIMTX/NOPB	ACTIVE	TSSOP	PW	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
DAC088S085CISQ	ACTIVE	WQFN	RGH	16	1000	TBD	CU SNPB	Level-1-260C-UNLIM	
DAC088S085CISQ/NOPB	ACTIVE	WQFN	RGH	16	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
DAC088S085CISQX	ACTIVE	WQFN	RGH	16	4500	TBD	CU SNPB	Level-1-260C-UNLIM	
DAC088S085CISQX/NOPB	ACTIVE	WQFN	RGH	16	4500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.





17-Nov-2012

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC088S085CIMTX	TSSOP	PW	16	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
DAC088S085CIMTX/NOP B	TSSOP	PW	16	2500	330.0	12.4	6.95	8.3	1.6	8.0	12.0	Q1
DAC088S085CISQ	WQFN	RGH	16	1000	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
DAC088S085CISQ/NOPB	WQFN	RGH	16	1000	178.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
DAC088S085CISQX	WQFN	RGH	16	4500	330.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1
DAC088S085CISQX/NOP B	WQFN	RGH	16	4500	330.0	12.4	4.3	4.3	1.3	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC088S085CIMTX	TSSOP	PW	16	2500	349.0	337.0	45.0
DAC088S085CIMTX/NOP B	TSSOP	PW	16	2500	349.0	337.0	45.0
DAC088S085CISQ	WQFN	RGH	16	1000	203.0	190.0	41.0
DAC088S085CISQ/NOPB	WQFN	RGH	16	1000	203.0	190.0	41.0
DAC088S085CISQX	WQFN	RGH	16	4500	349.0	337.0	45.0
DAC088S085CISQX/NOP B	WQFN	RGH	16	4500	349.0	337.0	45.0

PW (R-PDSO-G16)

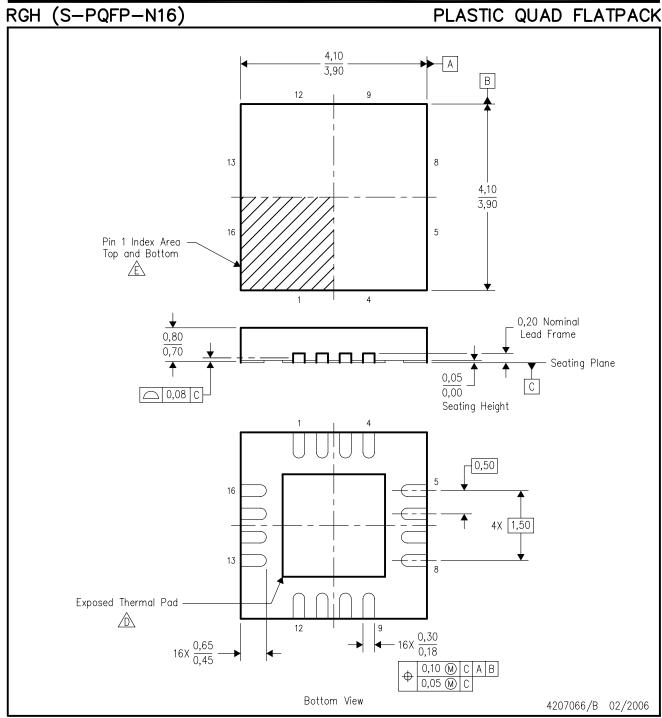
PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153

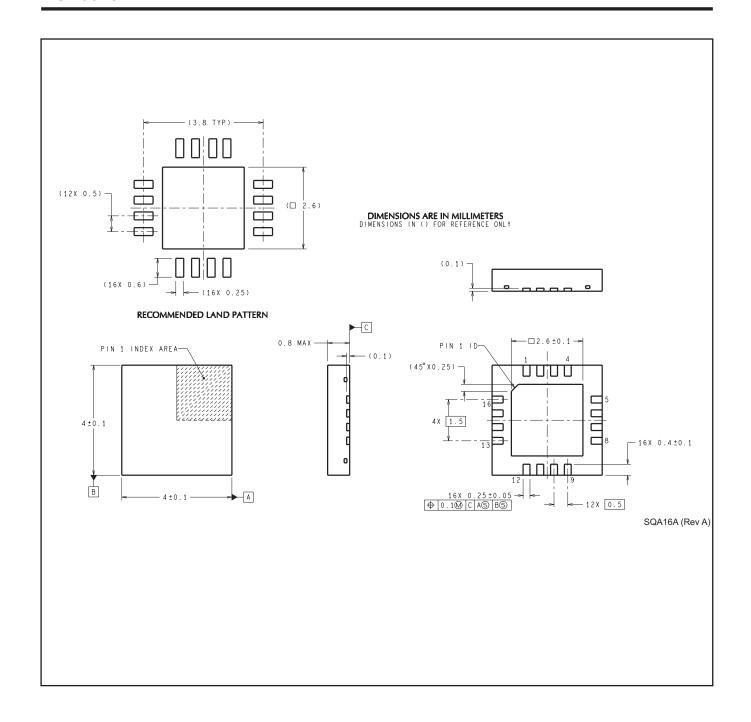




NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Complies to JEDEC MO-220 variation WGGD-4.





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